



# **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

50 A

### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@8A<9.5mΩ</li>
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@4A<14m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### **Mechanical Data**

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Weight: 0.0104 ounces, 0.297grams

# TO-252AA Drain Gate Source

# **Maximum Ratings and Thermal Characteristics** ( $T_A$ =25 $^{\circ}$ C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	50	А	
	T <sub>C</sub> =100°C		31		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	100		
Power Dissipation	T <sub>C</sub> =25°C	Po	64.9	W	
	T <sub>C</sub> =100°C		32.5	VV	
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	9.6	Α	
	T <sub>A</sub> =70°C		7.7		
Power Dissipation	T <sub>A</sub> =25°C	Po	2.4	10/	
	T <sub>A</sub> =70°C		1.6	W	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2.31	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1	1.7	2.5			
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =8A	-	8	9.5	mΩ		
		$V_{GS}$ =4.5V, $I_{D}$ =4A	-	11	14			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	-	1	uA		
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)			_			_		
Total Gate Charge	$Q_{g}$	V <sub>DS</sub> =20V, I <sub>D</sub> =8A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	22	-	nC		
Gate-Source Charge	$Q_{gs}$		-	4.2	-			
Gate-Drain Charge	$Q_{gd}$		-	4.0	-			
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	1258	-	pF		
Output Capacitance	Coss		-	134	-			
Reverse Transfer Capacitance	Crss	I=IIVIMZ	-	88	-			
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DS}$ =15V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =3.3 $\Omega$ (Note 2,3)	-	13	-			
Turn-On Rise Time	t <sub>r</sub>		-	14	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>		-	45	-			
Turn-Off Fall Time	t <sub>f</sub>		-	9	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			-	-	50	А		
Diode Forward Current	I <sub>S</sub>							
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1	V		

### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





### TYPICAL CHARACTERISTIC CURVES

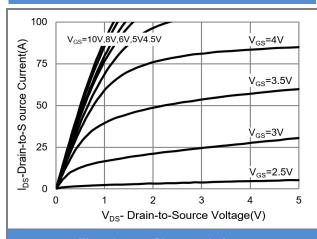
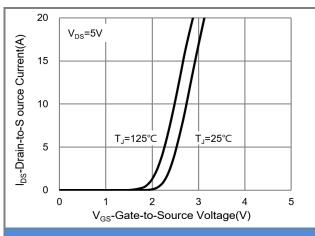


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

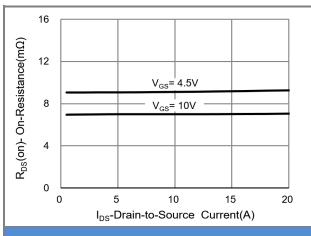


Fig.3 On-Resistance vs. Drain Current

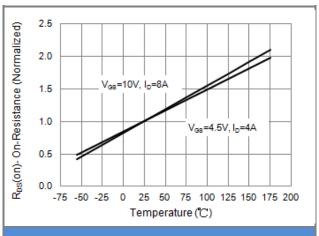
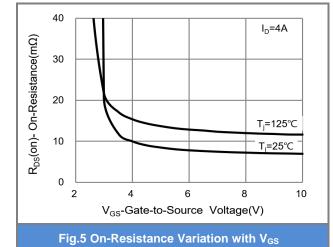


Fig.4 On-Resistance vs. Junction temperature



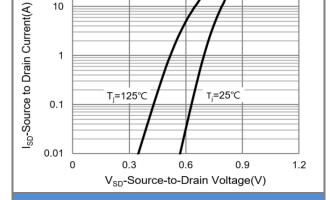


Fig.6 Source-Drain Diode Forward Voltage





### TYPICAL CHARACTERISTIC CURVES

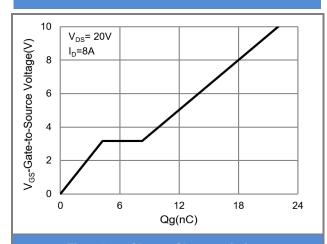


Fig.7 Gate-Charge Characteristics

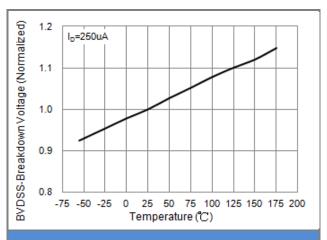


Fig.8 Breakdown Voltage Variation vs. Temperature

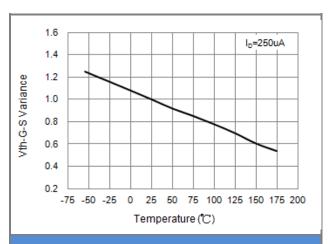


Fig.9 Threshold Voltage Variation with Temperature

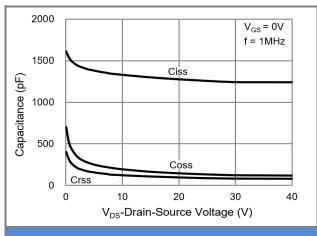
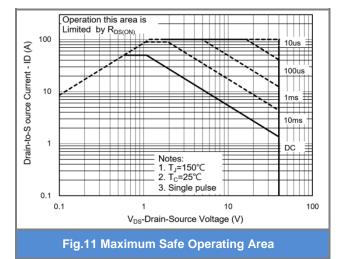
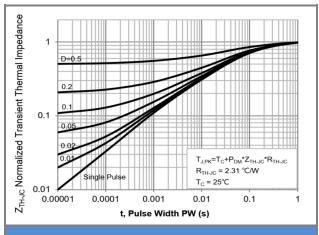


Fig.10 Capacitance vs. Drain-Source Voltage





**Fig.12 Normalized Transient Thermal Impedance** 

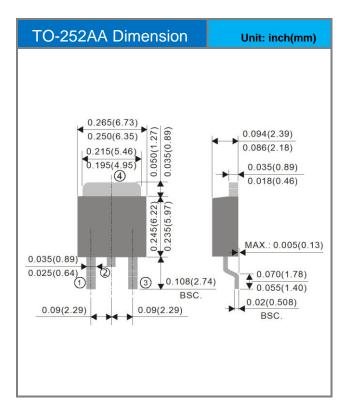


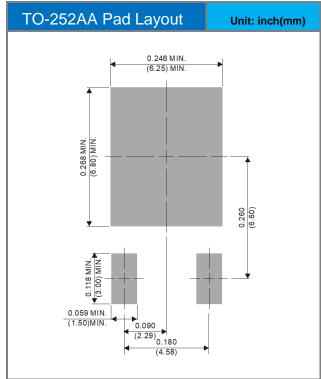


## **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJD50N04-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D50N04	Halogen free	

# **Packaging Information & Mounting Pad Layout**









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